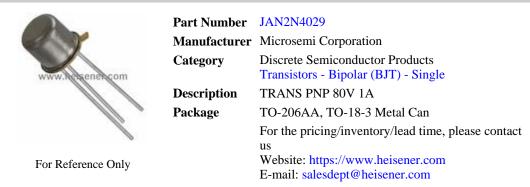


JAN2N4029

Request a Quote

JAN2N4029 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N4029 Specifications

Manufacturer Part Number	JAN2N4029
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-206AA, TO-18-3 Metal Can
Series	Military, MIL-PRF-19500/512
Transistor Type	PNP
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	80V
Vce Saturation (Max) @ Ib, Ic	1V @ 100mA, 1A
Current - Collector Cutoff (Max)	10μA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 100mA, 5V
Power - Max	500mW
Frequency - Transition	-
Operating Temperature	-55°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-206AA, TO-18-3 Metal Can
Supplier Device Package	TO-18 (TO-206AA)
	Report errors?

JAN2N4029 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N4029, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com